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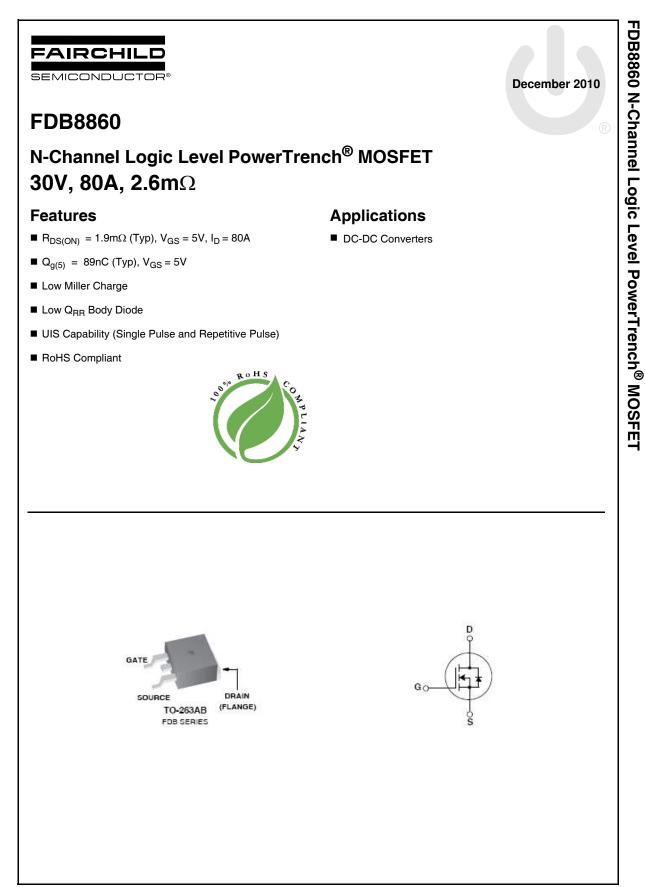


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| Symbol                            | Parameter  | Ratings     | Units |
|-----------------------------------|--|-------------|-------|
| V <sub>DSS</sub>                  | Drain to Source Voltage  | 30          | V     |
| V <sub>GS</sub>                   | Gate to Source Voltage   | ±20         | V     |
|                                   | Drain Current<br>Continuous ( $V_{GS} = 10V$ , $T_C < 163^{\circ}C$ )                    | 80          | А     |
| I <sub>D</sub>                    | Continuous ( $V_{GS} = 5V$ , $T_C < 162^{\circ}C$ )                                      | 80          | Α     |
|                                   | Continuous (V <sub>GS</sub> = 10V, T <sub>C</sub> = 25°C, with $R_{\theta JA}$ = 43°C/W) | 31          | Α     |
|                                   | Pulsed   | Figure 4    | A     |
| E <sub>AS</sub>                   | SinglePulseAvalancheEnergy (Note1)   | 947         | mJ    |
| Р                                 | Power Dissipation  | 254         | W     |
| P <sub>D</sub>                    | Derate above 25°C  | 1.7         | W/ºC  |
| T <sub>J</sub> , T <sub>STG</sub> | Operating and Storage Temperature  | -55 to +175 | °C    |

### **Thermal Characteristics**

| $R_{\theta JC}$ | Thermal Resistance Junction to Case  | 0.59 | °C/W |
|-----------------|--|------|------|
| $R_{\thetaJA}$  | Thermal Resistance Junction to Ambient (Note 2)                                | 62   | °C/W |
| $R_{	hetaJA}$   | Thermal Resistance Junction to Ambient TO-263,1in <sup>2</sup> copper pad area | 43   | °C/W |

## Package Marking and Ordering Information

| Device Marking | Device  | Package  | Reel Size | Tape Width | Quantity |
|----------------|---------|----------|-----------|------------|----------|
| FDB8860        | FDB8860 | TO-263AB | 330mm     | 24mm       | 800units |

## **Electrical Characteristics** $T_J = 25^{\circ}C$ unless otherwise noted

| Symbol            | Parameter                         | Test Conditions                    | Min | Тур | Max  | Units |
|-------------------|-----------------------------------|------------------------------------|-----|-----|------|-------|
| Off Chara         | acteristics                       |                                    |     |     |      |       |
| BV <sub>DSS</sub> | Drain to Source Breakdown Voltage | $I_D = 1mA, V_{GS} = 0V$           | 30  | -   | -    | V     |
| I                 | Zero Gate Voltage Drain Current   | $V_{DS} = 24V$                     | -   | -   | 1    |       |
| DSS               | Zero Gale Voltage Drain Guirent   | $V_{GS} = 0V$ $T_J = 150^{\circ}C$ | -   | -   | 250  | μΑ    |
| I <sub>GSS</sub>  | Gate to Source Leakage Current    | $V_{GS} = \pm 20V$                 | -   | -   | ±100 | nA    |

### On Characteristics

| V <sub>GS(th)</sub> | Gate to Source Threshold Voltage | $V_{DS} = V_{GS}, I_D = 250 \mu A$                                     | 1 | 1.7 | 3   | V  |
|---------------------|----------------------------------|--|---|-----|-----|----|
|                     |                                  | $I_{D} = 80A, V_{GS} = 10V$  | - | 1.6 | 2.3 |    |
|                     |                                  | $I_{D} = 80A, V_{GS} = 5V$   | - | 1.9 | 2.6 |    |
| R <sub>DS(ON)</sub> | Drain to Source On Resistance    | $I_{D} = 80A, V_{GS} = 4.5V$   | - | 2.1 | 2.7 | mΩ |
|                     |                                  | I <sub>D</sub> = 80A, V <sub>GS</sub> = 10V,<br>T <sub>J</sub> = 175°C | - | 2.5 | 3.6 |    |

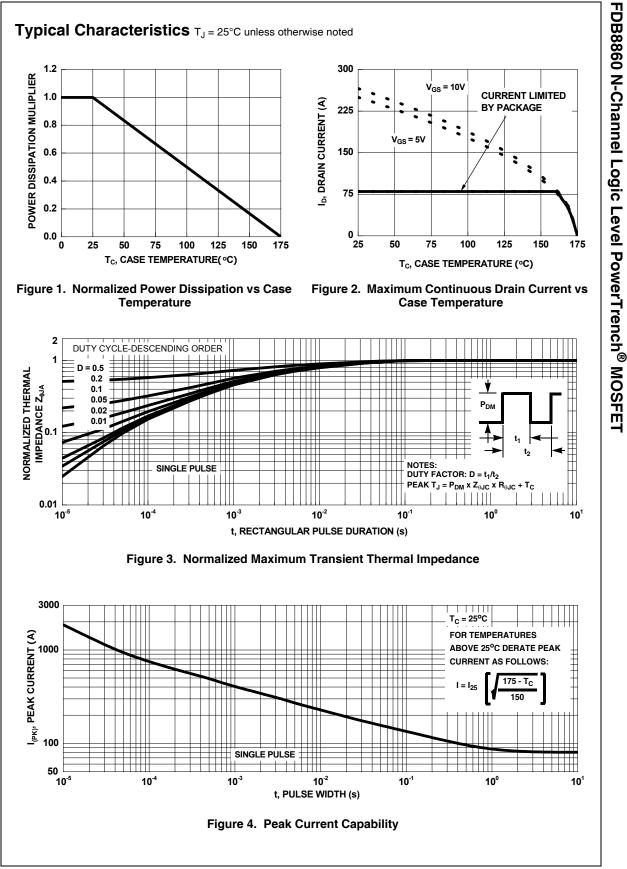
### **Dynamic Characteristics**

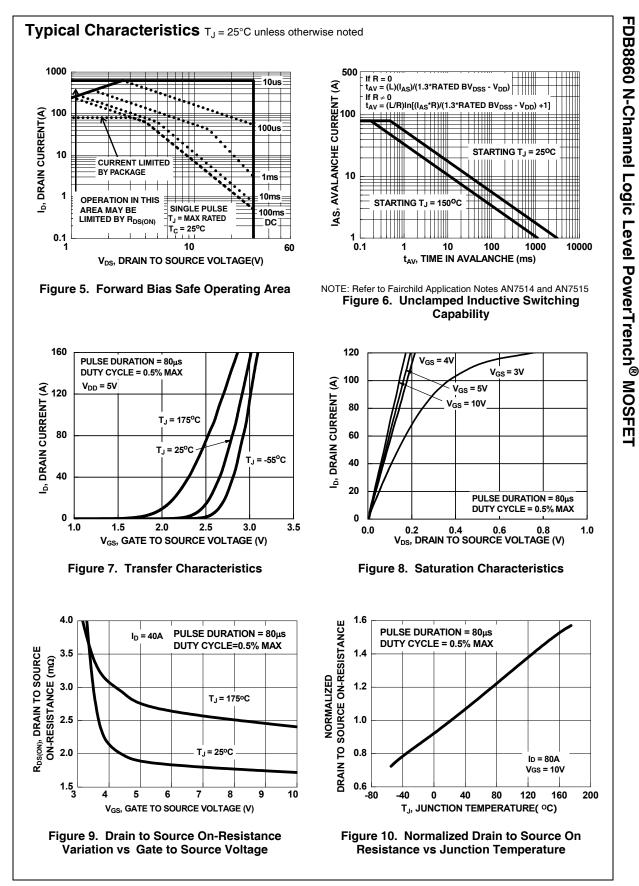
| CISS                | Input Capacitance                | V <sub>DS</sub> = 15V, V <sub>GS</sub> = 0V, |                                  | - | 9460 | 12585 | pF |
|---------------------|----------------------------------|--|----------------------------------|---|------|-------|----|
| C <sub>OSS</sub>    | Output Capacitance               |  |                                  | - | 1710 | 2275  | pF |
| C <sub>RSS</sub>    | Reverse Transfer Capacitance     |  |                                  | - | 1050 | 1575  | pF |
| R <sub>G</sub>      | Gate Resistance                  | f = 1MHz                                     |                                  | - | 1.8  | -     | Ω  |
| Q <sub>g(TOT)</sub> | Total Gate Charge at 10V         | V <sub>GS</sub> = 0V to 10V                  |                                  | - | 165  | 214   | nC |
| Q <sub>g(5)</sub>   | Total Gate Charge at 5V          | $V_{GS} = 0V \text{ to } 5V$                 |                                  | - | 89   | 115   | nC |
| Q <sub>g(TH)</sub>  | Threshold Gate Charge            | $V_{GS} = 0V$ to 1V                          | $V_{DD} = 15V$                   | - | 9.1  | 12    | nC |
| Q <sub>gs</sub>     | Gate to Source Gate Charge       |  | $I_{D} = 80A$<br>$I_{a} = 1.0mA$ | - | 26   | -     | nC |
| Q <sub>gs2</sub>    | Gate Charge Threshold to Plateau |  | ·g =                             | - | 18   | -     | nC |
| Q <sub>gd</sub>     | Gate to Drain "Miller" Charge    |  |                                  | - | 33   | -     | nC |

| Symbol              | Parameter           | Test Conditions   | Min | Тур | Max | Units |
|---------------------|---------------------|---|-----|-----|-----|-------|
| Switching           | g Characteristics   |   |     |     |     |       |
| t <sub>(on)</sub>   | Turn-On Time        |   | -   | -   | 340 | ns    |
| t <sub>d(on)</sub>  | Turn-On Delay Time  | V <sub>DD</sub> = 15V, I <sub>D</sub> = 80A<br>V <sub>GS</sub> = 5V, R <sub>GS</sub> = 1Ω | -   | 14  | -   | ns    |
| t <sub>r</sub>      | Turn-On Rise Time   |   | -   | 213 | -   | ns    |
| t <sub>d(off)</sub> | Turn-Off Delay Time |   | -   | 79  | -   | ns    |
| t <sub>f</sub>      | Turn-Off Fall Time  |   | -   | 49  | -   | ns    |
| t <sub>off</sub>    | Turn-Off Time       |   | -   | -   | 192 | ns    |

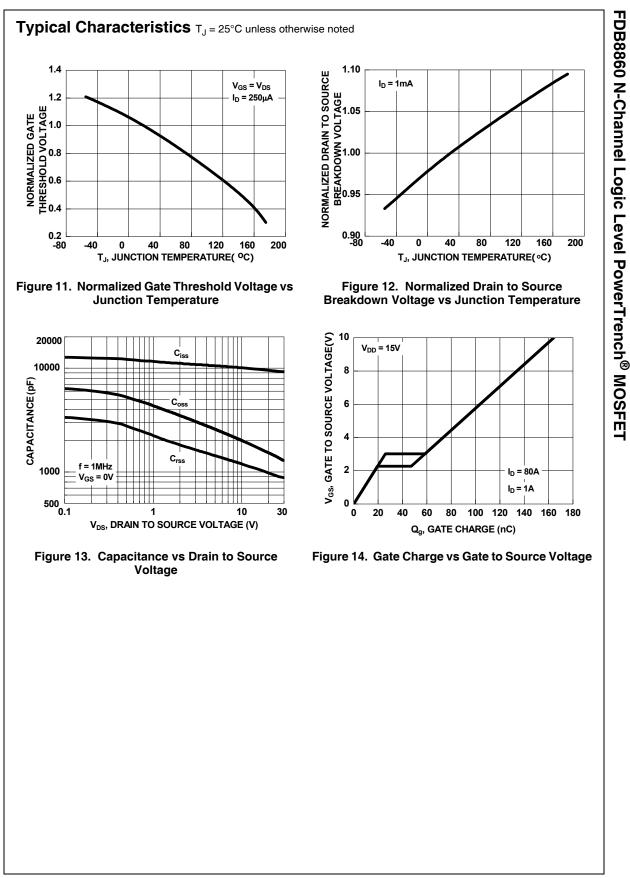
| V               | Source to Drain Diode Voltage | $I_{SD} = 80A$                             | - | - | 1.25 | v  |
|-----------------|-------------------------------|--|---|---|------|----|
| VSD             | Source to Drain Diode Voltage | I <sub>SD</sub> = 40A                      | - | - | 1.0  | V  |
| t <sub>rr</sub> | Reverse Recovery Time         | $I_{SD} = 80A$ , $dI_{SD}/dt = 100A/\mu s$ | - | - | 43   | ns |
| Q <sub>rr</sub> | Reverse Recovery Charge       | $I_{SD} = 80A$ , $dI_{SD}/dt = 100A/\mu s$ | - | - | 29   | nC |

Notes: 1: Starting  $T_J = 25^{\circ}$ C, L =0.47mH, I<sub>AS</sub> = 64A , V<sub>DD</sub> = 30V, V<sub>GS</sub> = 10V. 2: Pulse width = 100s





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